

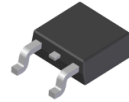
FEATURE

- Low gate charge
- Low C_{iss}
- Fast switching
- 100% avalanche tested
- Improved dv/dt capability

Maximum output current
 I_{OM} : 0.5 A

Output voltage
 V_O : 15V

Continuous total dissipation
 P_D : 1.25 W ($T_a = 25^\circ\text{C}$)



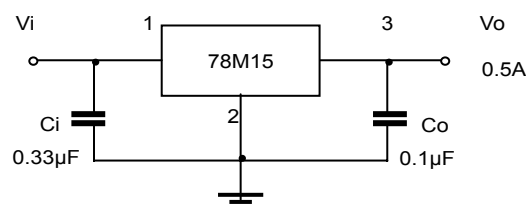
ABSOLUTE MAXIMUM RATINGS (Operating temperature range applies unless otherwise specified)

Parameter	Symbol	Value	Unit
Input Voltage	V_i	25	V
Operating Junction Temperature Range	T_{OPR}	0-+125	$^\circ\text{C}$
Storage Temperature Range	T_{STG}	-65-+150	$^\circ\text{C}$

ELECTRICAL CHARACTERISTICS AT SPECIFIED VIRTUAL JUNCTION TEMPERATURE

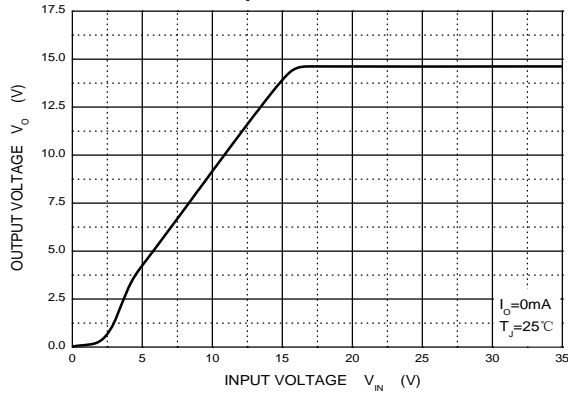
Parameter	Symbol	Test conditions	Min	Typ	Max	Unit	
Output Voltage	V_o	$V_i=23\text{V}, I_o=350\text{mA}$	25 $^\circ\text{C}$	14.4	15	15.6	V
		$17.5 \leq V_i \leq 30\text{V}, I_o=5\text{mA} \sim 350\text{mA}$ $P_o \leq 15\text{W}$	0-125 $^\circ\text{C}$	14.25	15	15.75	V
Load Regulation	ΔV_o	$I_o=5\text{mA} \sim 500\text{mA}$	25 $^\circ\text{C}$			300	mV
		$I_o=5\text{mA} \sim 200\text{mA}$	25 $^\circ\text{C}$			150	mV
Line Regulation	ΔV_o	$17.5\text{V} \leq V_i \leq 30\text{V}, I_o=200\text{mA}$	25 $^\circ\text{C}$			100	mV
		$20\text{V} \leq V_i \leq 26\text{V}, I_o=200\text{mA}$	25 $^\circ\text{C}$			50	mV
Quiescent Current	I_q	$V_i=23\text{V}, I_o=350\text{mA}$	25 $^\circ\text{C}$		6	mA	
Quiescent Current Change	ΔI_q	$17.5\text{V} \leq V_i \leq 30\text{V}, I_o=200\text{mA}$	0-125 $^\circ\text{C}$			0.8	mA
	ΔI_q	$V_i=23\text{V}, I_o=5\text{mA} \sim 350\text{mA}$	0-125 $^\circ\text{C}$			0.5	mA
Output Noise Voltage	V_N	$10\text{Hz} \leq f \leq 100\text{KHz}$	25 $^\circ\text{C}$		90	μV	
Ripple Rejection	RR	$18.5 \leq V_i \leq 28.5\text{V}, f=120\text{Hz}, I_o=300\text{mA}$	0-125 $^\circ\text{C}$	54		dB	
Dropout Voltage	V_d		25 $^\circ\text{C}$		2	V	

TYPICAL APPLICATION

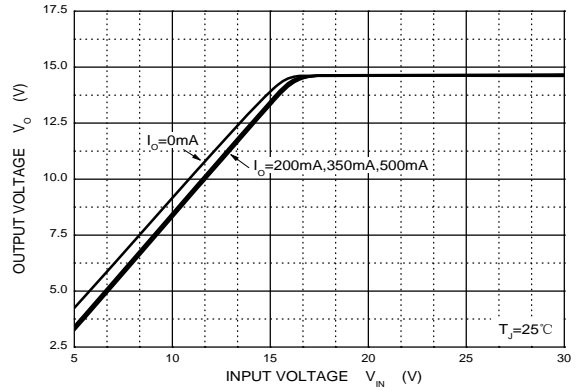


RATING AND CHARACTERISTIC CURVES

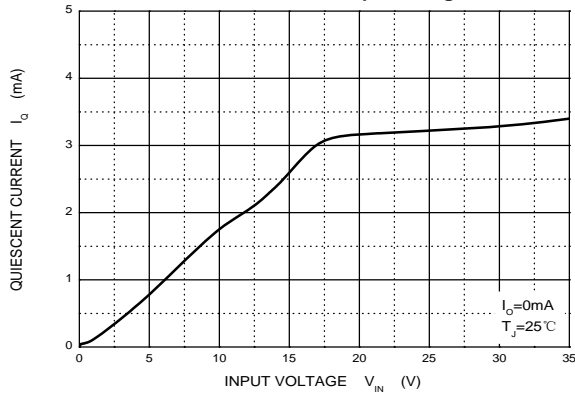
Output Characteristics



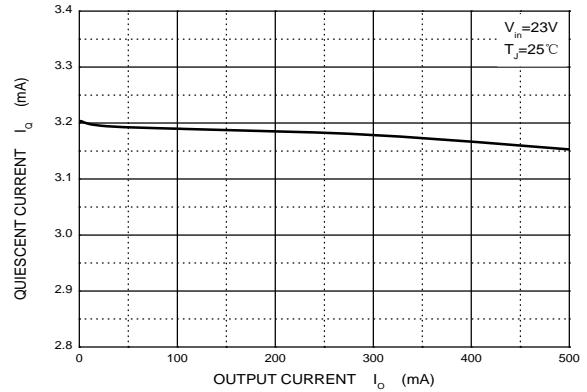
Dropout Characteristics



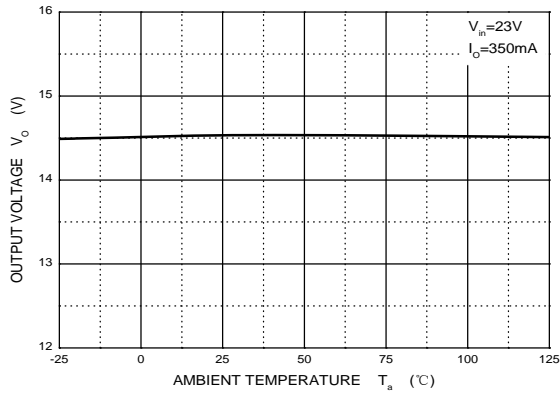
Quiescent Current vs Input Voltage



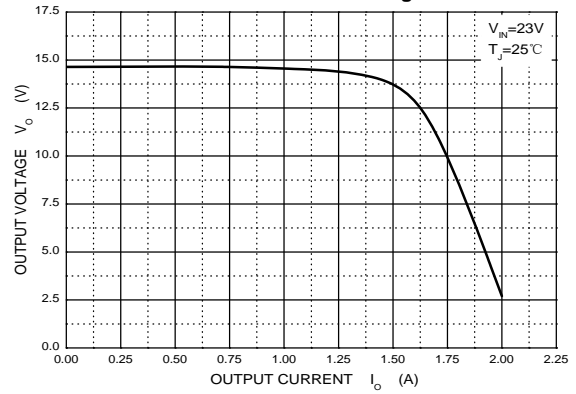
Quiescent Current vs Output Current



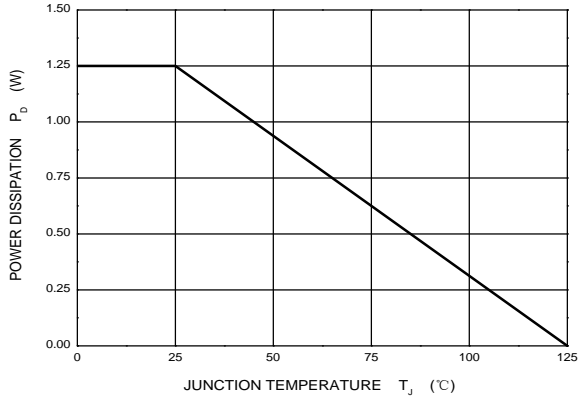
Output Voltage vs Ambient Temperature



Current Cut-off Grid Voltage



Power Derating Curve



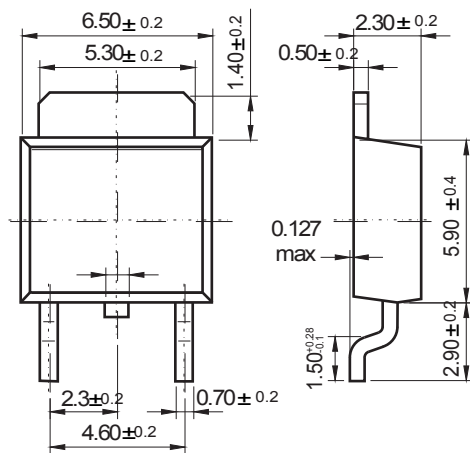
Soldering parameters

Reflow Condition		Pb-Free assembly (see as below)
Pre Heat	-Temperature Min ($T_{s(min)}$)	+150 °C
	-Temperature Max ($T_{s(max)}$)	+200 °C
	-Time (Min to Max) (ts)	60-180 secs.
Average ramp up rate (Liquid us Temp (T_L) to peak)		3 °C/sec. Max
$T_{s(max)}$ to T_L - Ramp-up Rate		3 °C/sec. Max
Reflow	-Temperature (T_L) (Liquid us)	+217 °C
	-Temperature (t_L)	60-150 secs.
Peak Temp (T_P)		+260(+0/-5) °C
Time within 5 °C of actual Peak Temp (t_p)		30 secs. Max
Ramp-down Rate		6 °C/sec. Max
Time 25 °C to Peak Temp (T_P)		8 min. Max
Do not exceed		+260 °C

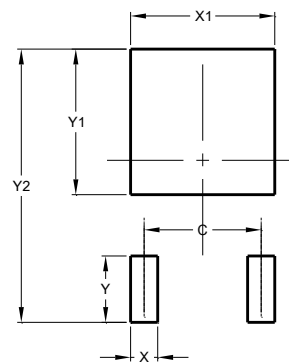


Package Dimensions & Suggested Pad Layout

TO-252



Dimensions in inches and (millimeters)



Dimensions	Value (in mm)
C	4.55
X	1.50
X1	5.80
Y	2.70
Y1	6.00
Y2	10.90

Tape & reel specification

Tape		Symbol	Dimension (mm)		
		P0	4.00±0.20		
		P1	8.00±0.20		
		P2	2.00±0.20		
		D0	1.55±0.15		
		D1	1.55±0.20		
		E	1.75±0.20		
		F	7.50±0.20		
		W	16.00±0.20		
		A0	7.10±0.20		
		B0	10.50±0.20		
		K0	2.70±0.20		
		T	0.30±0.10		
		13" Reel		D2	330.0±5.0
				D3	100.0±4.0
W1	20.0±5.0				
W2	25.0±5.0				
I	13.0±2.0				
Quantity: 2500PCS					